

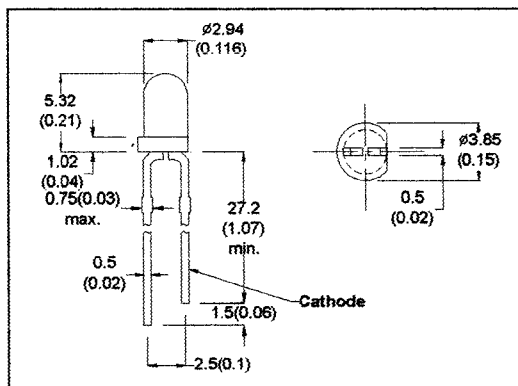
MICRO ELECTRONICS

MSB32DA-X (MSB32DA)

ULTRA HIGH BRIGHTNESS RED LED LAMP

DESCRIPTION

MSB32DA-X is ultra high brightness GaAlAs red LED lamp encapsulated in a 3mm diameter red diffused lens. 6 brightness grouping is provided for customer's selection.



- All Dimension in mm (inch)
- No Scale
- Tol : + / - 0.3mm

ABSOLUTE MAXIMUM RATINGS

Power Dissipation @Ta=25°C	100mW
Forward Current, DC (IF)	40mA
Reverse Voltage	5V
Operating & Storage Temperature Range	-55 to +100°C
Lead Soldering Temperature (1/16" from body)	260°C for 5 sec.

ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
Forward Voltage	VF		1.8	2.4	V	IF=20mA
Reverse Breakdown Voltage	BVR	5			V	IR=100 μ A
Luminous Intensity	IV				mcd	IF=20mA
		15	25		mcd	IF=20mA
MSB32DA & -0		30	45		mcd	IF=20mA
-1		40	55		mcd	IF=20mA
-2		55	70		mcd	IF=20mA
-3		70	85		mcd	IF=20mA
-4		85	120		mcd	IF=20mA
-5					mcd	IF=20mA
Peak Wavelength	λ_p		660		nm	IF=20mA
Spectral Line Half Width	$\Delta\lambda$		20		nm	IF=20mA
Viewing Angle	2 θ 1/2		50		degree	IF=20mA

MICRO ELECTRONICS LTD.

38, Hung To Road, Microtron Building, Kwun Tong, Kowloon, Hong Kong.
Kwun Tong P.O. Box 69477 Hong Kong. Fax No. 2341 0321 Telex:43510 Micro Hx. Tel: 2343 0181-5

Aug-99